

03-03-2008

Form PTO-1595
(Rev. 10/02)
OMB No. 0651-0027 (exp. 6/30/2005)
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Attached original documents or copy thereof.

2-2-08

To the Honorable Commissioner

1. Name of conveying party(ies):

Fwu-Iuan Hshieh

Additional name(s) of conveying party(ies) attached? Yes No

3. Nature of conveyance:

- Assignment Merger
- Security Agreement Change of Name
- Other _____

Execution Date: November 2, 2007

2. Name and address of receiving party(ies)

Name: Force-MOS Technology Corporation

Internal Address: _____

Street Address: 4F-5, No.83, Sec.2

Dongda Road

City: Hsinchu, Taiwan, R. O. C. State: _____ Zip: _____

Additional name(s) & address(es) attached? Yes No

4. Application number(s) or patent number(s):

If this document is being filed together with a new application, the execution date of the application is: Nov. 12, 2007

A. Patent Application No.(s)

B. Patent No.(s)

Additional numbers attached? Yes No

5. Name and address of party to whom correspondence concerning document should be mailed:

Name: Bo-In Lin

Internal Address: _____

Street Address: 13445 Mandoli Drive

City: Los Altos Hills, CA State: CA Zip: 94022

6. Total number of applications and patents involved: 1

7. Total fee (37 CFR 3.41).....\$ 40.00

- Enclosed, included in PT02038 form
- Authorized to be charged to deposit account

8. Deposit account number:

(Attach duplicate copy of this page if paying by deposit account)

DO NOT USE THIS SPACE

9. Statement and signature.

To the best of my knowledge and belief, the foregoing information is true and correct and any attached copy is a true copy of the original document.

Ching-lu Lin
Name of Person Signing

Ching-lu Lin
Signature

Feb. 20, 2008
Date

Total number of pages including cover sheet, attachments, and documents: 2

Mail documents to be recorded with required cover sheet information to:
Commissioner of Patents & Trademarks, Box Assignments
Washington, D.C. 20231

ASSIGNMENT

INVENTOR
AND CITY

Whereas, I, Fwu-Iuan Hshieh of 20768 Sevilla Lane,
Saratoga, California 95070

have invented:

TITLE:

TRENCH MOSFET WITH DOUBLE EPITAXIAL STRUCTURE

DATE INVENTOR
SIGNED THE
DECLARATION

and executed a United States patent application therefor
on Nov. 2, 2007;

Whereas, Force-MOS Technology Corporation, having a place
of business at Hsinchu, Taiwan (hereinafter called FMTC), desires to
acquire the entire right, title and interest of said application and
invention, and to any United States and foreign patents to be obtained
therefor;

Now therefore, for a valuable consideration, receipt whereof is
hereby acknowledged, I, the above named, hereby sell, assign, and
transfer to FMTC, its successors and assigns, the entire right, title and
interest in the said application and invention therein disclosed for the
United States and foreign countries, and all rights of priority resulting
from the filing said United States application, and I request the
Commissioner of Patents to issue any Letters Patent granted upon the
inventions set forth in said application to FMTC its successors and
assigns; and I hereby agree that FMTC may apply for foreign Letters
Patent on said invention and I will execute all papers necessary in
connection with the United States and foreign applications when called
upon to do so by

CITY AND

Signed and Sealed at Shanghai, China

DATE

on Nov. 2, 2007.



SIGNATURE OF INVENTOR